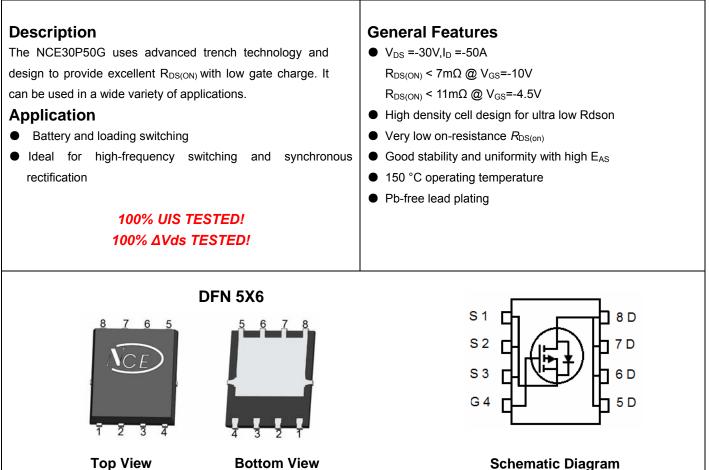


NCE P-Channel Enhancement Mode Power MOSFET



Bottom View

Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE30P50G	NCE30P50G	DFN 5x6-8L	-	-	-

Absolute Maximum Ratings (T_c=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	-30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	-50	А
Pulsed Drain Current	I _{DM}	-200	A
Maximum Power Dissipation	PD	65	W
Derating factor		0. 52	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	900	mJ
Operating Junction and Storage Temperature Range	T_{J},T_{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ extsf{ heta}JC}$	1.92	°C /W



Electrical Characteristics (TC=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	····		·	•		
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30	-33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, I _D =-250µA	-1	-1.5	-2.2	V
Durain Course On Chata Desintance	P	V _{GS} =-10V, I _D =-20A	-	5.5	7	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =-4.5V, I _D =-20A	-	7	11	mΩ
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-20A	-	50	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}		-	7016	-	PF
Output Capacitance	C _{oss}	V_{DS} =-15V, V_{GS} =0V,	-	838	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	616	-	PF
Switching Characteristics (Note 4)	I					
Turn-on Delay Time	t _{d(on)}		-	13	-	nS
Turn-on Rise Time	tr	V _{DD} =-15V,I _D =-20A	-	16	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10V, R_{GEN} =6 Ω	-	80	-	nS
Turn-Off Fall Time	t _f		-	45	-	nS
Total Gate Charge	Qg		-	92.5	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-15V,I _D =-20A,	-	11.5	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	17	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-20A	-	-0.85	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-50	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = -20A	-	35	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	50	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

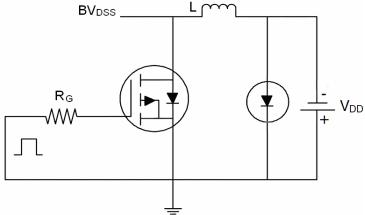
3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

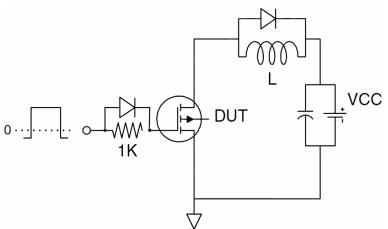
5. EAS condition: Tj=25 $^\circ C$,V_DD=-15V,V_G=-10V,L=0.5mH,Rg=25\Omega



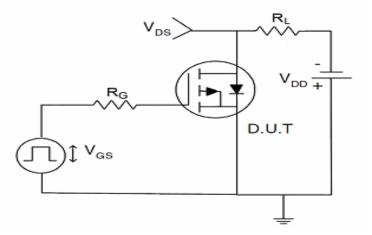
Test Circuit 1) E_{AS} Test Circuit



2) Gate Charge Test Circuit

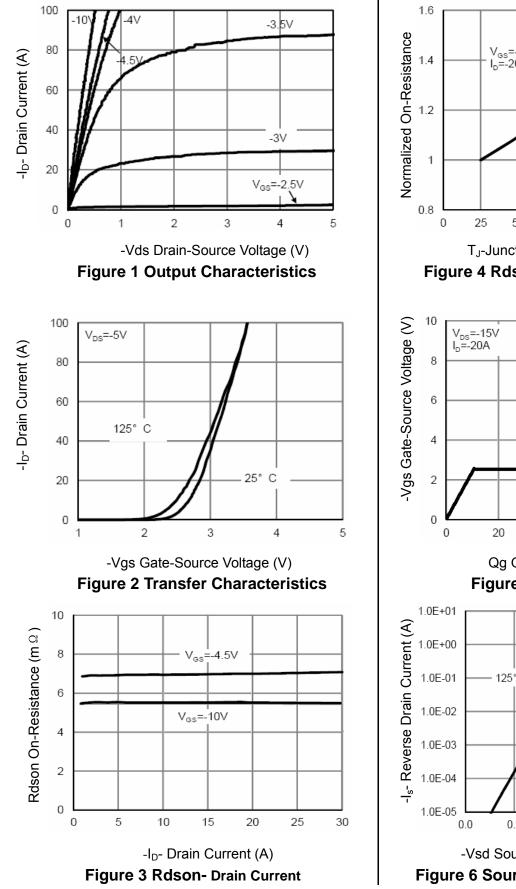


3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)



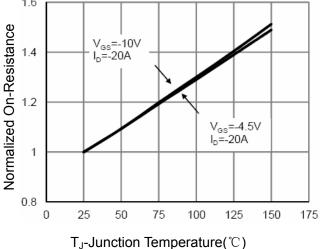
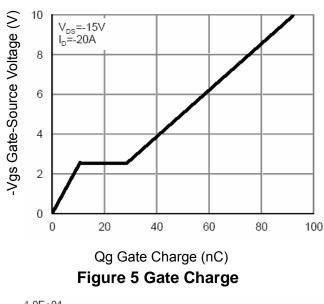


Figure 4 Rdson-Junction Temperature



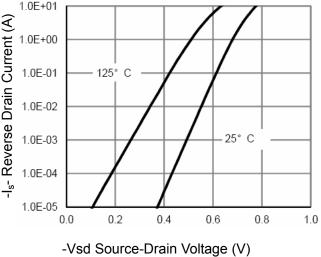
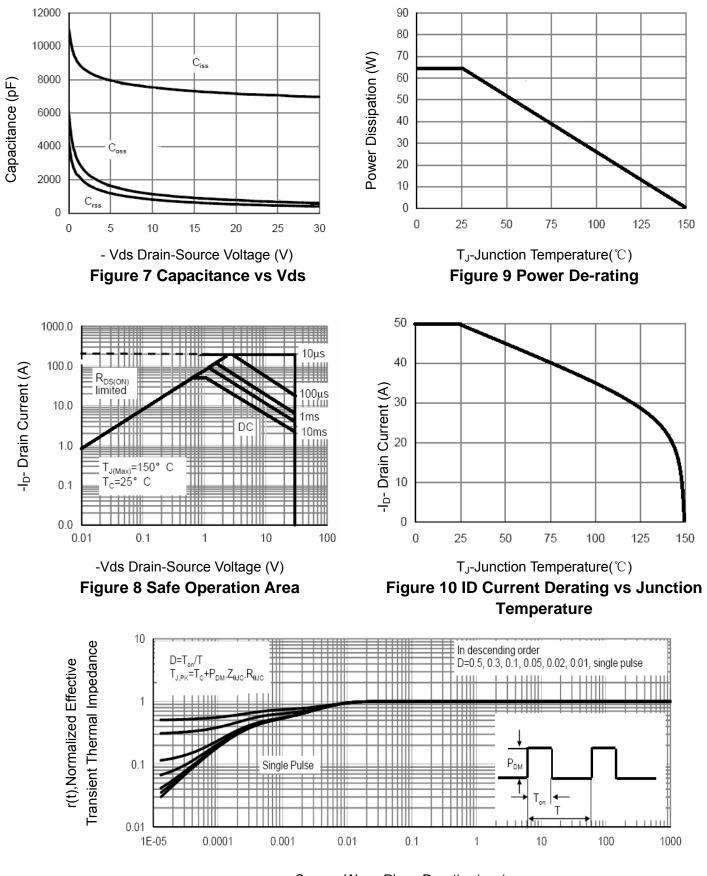


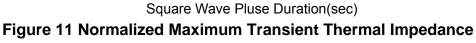
Figure 6 Source- Drain Diode Forward



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NCE30P50G

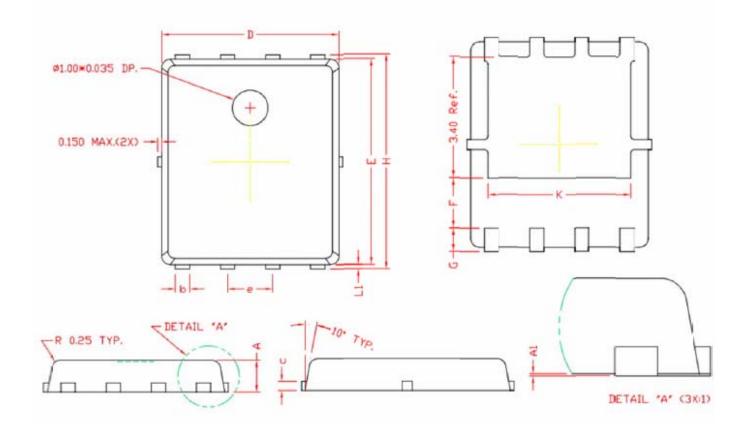






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DFN5X6-8L Package Information



COMMON DIMENSIONS

SYMBOL	MIN	NOM	MAX	
A	0.80	0.90	1.00	
A1	0.00	0.03	0.05	
b	0.35	0.42	0.49	
с	0.254 REF.			
D	4.90	5.00	5.10	
F	1.40 REF.			
E	5.70	5.80	5.90	
е	1	. 27 BSC		
Н	5.95	6.08	6.20	
L1	0.10	0.14	0.18	
G	G 0.60 REF. K 4.00 REF.			
K				

(UNITS OF MEASURE=MILLIMETER)



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